

NuPower Xtender™ LS10S01-D30 L- & S-Band Bidirectional Amplifier

25 Watt CW 10 Watts Linear, 5% EVM [QPSK] 1.0 GHz - 2.5 GHz

P/N: NW-BA-LS-10-S01-D30

(includes NW-BA-ACC-CB09MA)

Contact sales@nuwaves.com for custom options



The NuPower Xtender™ LS10S01-D30 is a small, lightweight, and power-efficient bidirectional amplifier ideal for extending the communication range of half-duplex L- or S-band transceivers running constant-envelope or near-constant-envelope waveforms. The bidirectional amplifier typically generates 25 Watts of RF power from 1000 to 2500 MHz in transmit mode and the integrated low-noise amplifier typically provides 14 dB of gain in receive mode.

Based on the latest gallium nitride (GaN) technology, the Xtender typically offers 39% power efficiency at most frequencies and its compact size makes it ideal for integration into space-constrained platforms. Adjacent radio frequency bands, such as the popular 900 MHz Industrial, Scientific and Medical (ISM) band, are also supported by the bidirectional PA, at lower peak power levels.

Accepting a nominal +30 dBm RF input, the Xtender typically provides 14 dB of gain. The Xtender also features over-voltage and reverse-voltage protection and operates over a wide temperature range of -40 to +85 °C baseplate.

Extend your operational communication range with NuPower™ amplifiers from **NuWaves RF Solutions.**

Features

- 25 Watts (typ) RF Output Power
- 1.0 to 2.5 GHz
- Bidirectional Operation
- 14 dB (typ) of Transmit Gain
- 14 dB (typ) Receive Gain
- Fast T/R Mode Switching with Auto-Sensing or Manual T/R Line
- Small Form Factor
- High Efficiency GaN Technology
- Over-Voltage & Reverse-Voltage Protection

Applications

- Unmanned Aircraft Systems (UAS) -Group 2 and Group 3
- Unmanned Ground Vehicles (UGV)
- Software Defined Radios
- Air Launch Effect (ALE)
- Common Launch Tube (CLT)
- Counter UAS Detection and Mitigation
- MIMO/MANET Radio Range Extension
- SISO Radio Range Extension









Specifications

Absolute Maximums

Parameter	Rating	Unit			
Max Device Voltage	32	V			
Max Device Current	3.5	А			
May DE Input Dougr CW 7 — 50 0	XCVR Port: +33	dBm			
Max RF Input Power, CW, $Z_L = 50 \Omega$	ANT Port ¹ :+30	UDIII			
Max Operating Temperature (ambient)	60	%			
Max Operating Temperature (baseplate)	85	°C			
Max Storage Temperature	85	°(

Export Classification

ECCN 5A991G

Electrical Specifications - Operational @ 28 VDC, 25 °C, $Z_S = Z_L = 50 \Omega$, CW, Pin = + 30 dBm (unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Operating Frequency	BW	1000		2500	MHz	
			0.95	1.95		Rx – Tx (Manual T/R)
Switching Speed	TV		1.3	1.5	c	Tx - Rx (Manual T/R)
	TX _{ON/OFF}		1.3	1.5	- μS	Rx – Tx (Autosense)
			1.6	2.0		Tx - Rx (Autosense)
Operating Voltage	VDC	11	28	32	V	
Operating Current (Transmit)	I _{DD}		2.3	3.5	A	
Module Efficiency (Transmit)			39		%	

Electrical Specifications - Transmit @ 28 VDC, 25 °C, Z_S=Z_L=50 Ω, CW, Pin = +30 dBm (unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
RF Output Power, Linear	PL		10		W	QPSK, 1 Msps, 35% Filter
RF Output Power, Psat	Psat	10	25		W	
Transmit Gain	G		14		dB	
Power Gain Flatness	ΔG		±1.1		dB	1-2.5 GHz
Small Signal Gain Flatness	ΔG		±2.5		dB	Pin= 0 dBm, 1-2.5 GHz
Harmonics	2nd		-18		JD -	
Harmonics	3rd		-22		- dBc	
Nominal Input Drive Level	P _{IN}		30	33	dBm	
Quiescent Current	l _{DQ}		75		mA	T/R Enable Off (Receive Current)
Transmit Current	I _{TX}		2.5	3.5	A	
Transmit Input VSWR (XCVR Port)	VSWR		2:1			
Transmit Output Mismatch VSWR	VSWR			10:1	Ψ	No damage at all phase angles

Electrical Specifications - Receive @ 28 VDC, 25 °C, Z_S=Z_L=50 Ω, CW, -30 dBm Input Power (unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Receive Gain	G	12	14		dB	
Receive P1dB	P1dB		16		dBm	Pin=+3 dBm (typ)
Receive Gain Flatness	ΔG		±1		dB	1-2.5 GHz

¹Max operational receive input power = -20 dBm

Specifications (cont.)

Electrical Specifications - Receive (cont.) @ 28 VDC, 25 °C, Z₅=Z_L=50 Ω, CW, -30 dBm Input Power (unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Receive Current	I _{RX}		75		mA	
Receive Noise Figure	NF		2.1		dB	
Receive Input VSWR (ANT Port)	VSWR		1.6:1			

Mechanical Specifications

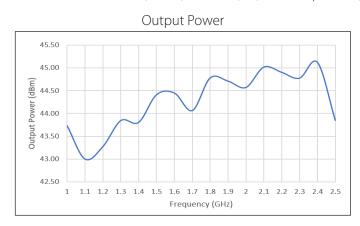
Parameter	Value	Unit	Limits	
Dimensions	3.0 x 2.0 x 0.65	in	Max	
Weight	4	0Z	Max	
RF Connectors, Input/Output	SMA Female			
Interface Connector	Micro-D, 9-pin Socket			
Cooling	Adequate Heatsink Required			

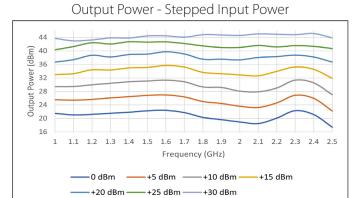
Environmental Specifications

Environmental speemeations					
Parameter	Symbol	Min	Тур	Max	Unit
Operating Temperature (ambient)	T _A	-40		+60	°C
Operating Temperature (baseplate)	Tc	-40		+85	°C
Storage Temperature	T _{STG}	-55		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude MIL-STD-810F - Method 500.4	ALT			30,000	ft
Vibration / Shock Profile (Random profile in x,y, z axis, as per Figure for 15 minute duration in each axis)	Power Spectral Density, g ² /Hz	*3 tt8/oct2	0.04 g	ਤੇ/Hz ਤੋ	78/o _{Ctave}
			Freque	ncy, Hz	

Transmit Performance Plots

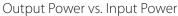
Test Conditions: +28 VDC, +25 °C, $Z_S=Z_L=50$ Ω , CW, +30 dBm Input Power (unless otherwise specified)

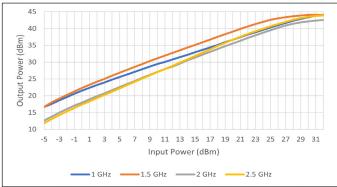




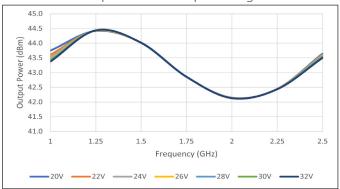
Transmit Performance Plots (cont.)

Test Conditions: +28 VDC, +25 °C, $Z_S=Z_L=50$ Ω , CW, +30 dBm Input Power (unless otherwise specified)

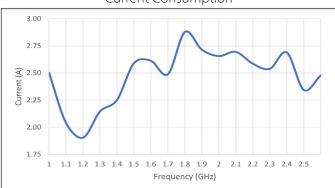




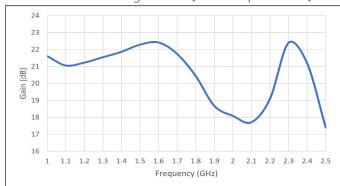
Output Power vs. Input Voltage



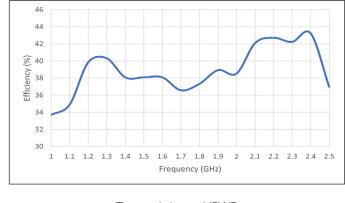
Current Consumption



Transmit Small Signal Gain [0 dBm Input Power]



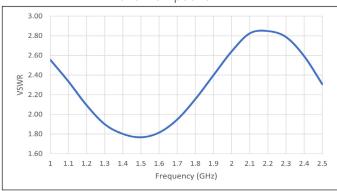
Efficiency



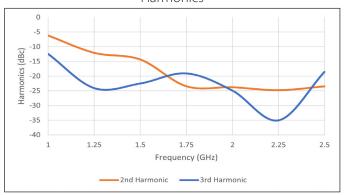
Efficiency vs. Output Power



Transmit Input VSWR



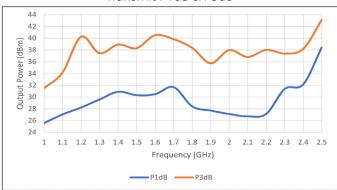
Harmonics



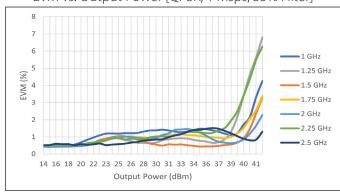
Transmit Performance Plots (cont.)

Test Conditions: +28 VDC, +25 °C, $Z_S=Z_L=50$ Ω , CW, +30 dBm Input Power (unless otherwise specified)

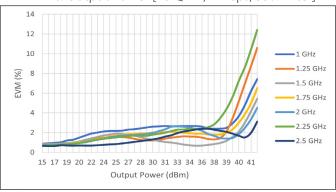




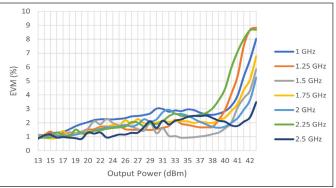
EVM vs. Output Power [QPSK, 1 Msps, 35% Filter]



EVM vs. Output Power [16 QAM, 2 Msps, 35% Filter]

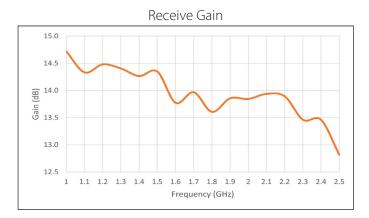


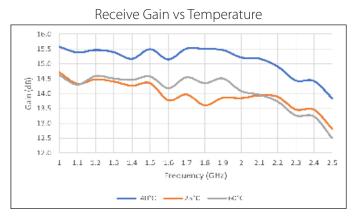
EVM vs. Output Power [64 QAM, 5 Msps, 10% Filter]

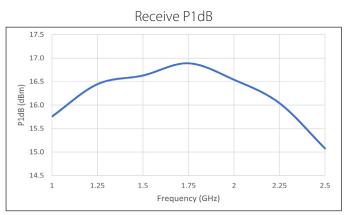


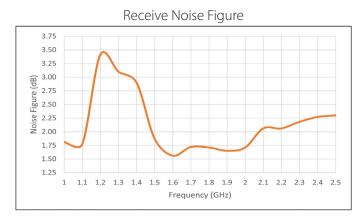
Receive Performance Plots

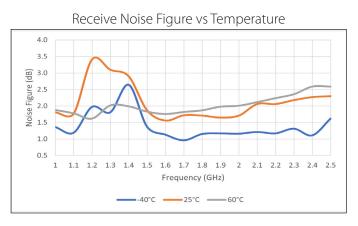
Test Conditions: +28 VDC, +25 °C, Z_S = Z_L =50 Ω , CW, -30 dBm Input Power (unless otherwise specified)

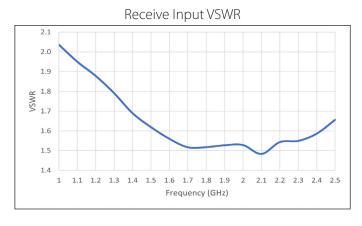




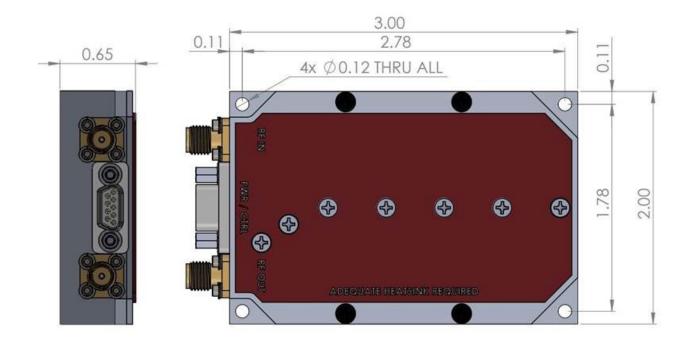






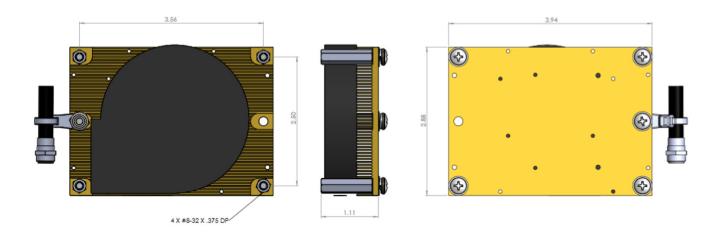


Mechanical Outline



Optional Heatsink Drawing

Heatsink and Integrated Fan: HTSK-01



Accessory Part Numbers

Part Number	Description
<u>NW-FL-05LPLE-2500-</u> <u>SFSF-M01</u>	Harmonic Filter Module
NW-BA-ACC-CB09MA	Standard Interface Cable Assembly – Flying Leads (included with module)
NW-BA-ACC-CT09MA	Upgraded Interface Cable Assembly – Banana Plug Termination
HTSK-01	Heatsink with Integrated Fan

For information on product disposal (end-of-life), please refer to this document: https://nuwaves.com/wp-content/uploads/Product-Disposal-End-of-Life.pdf

Pinout

Function	I/O	Pin	Logic Voltage
DC Power (Primary Power, +11 to +32 Volts)	I	1, 2, 9	-
Ground (DC Return)	I	3, 4, 5	-
RS-485 Data Transmit	0	6	-
RS-485 Data Receive	I	7	-
T/R Enable	1/0	8	3.3V Logic ² High: 2.31 - 3.8 VDC Low: -0.5 - 0.99 VDC
T/R Mode: Source (Autosense) ¹ T/R Mode: Sink (Manual T/R) [High TX / Low RX]	1/0	ŏ	5V Logic ² High: 3.5 - 5.5 VDC Low: -0.5 - 1.5 VDC

¹Autosense automatically switches to transmit and receive based on input signal strength. Typical threshold is 0 dBm; see user manual for complete information.

Contact NuWaves



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²Logic level configurable by user or factory. Default logic level is 3.3V.